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LATENT CATALYST, THERMOSETTING RESIN COMPOSITION COMPRISING
THE CATALYST, EPOXY RESIN MOLDING MATERIAL COMPRISING THE
CATALYST, AND SEMICONDUCTOR DEVICE

BACKGROUND OF THE INVENTION

FIELD OF THE INVENTION

This invention relates to a latent catalyst
extremely excellent in moisture resistance reliability,
5 curability and storage stability at ordinary temperature, a
thermosetting resin composition comprising the same, an
epoxy resin molding material for encapsulating a semi-
conductor responding to insertion mounting and surface
mounting which molding material comprises the above latent
10 catalyst and is excellent in moisture resistance
reliability, storage stability at ordinary temperature and
moldability, and a semiconductor device in which the
molding material is used.

RELATED ART STATEMENT

15 Thermosetting resins have been required to have a
storage stability at ordinary temperature for the purpose
of simplifying the handling thereof, and various latent
catalysts have been developed by now. The latent catalyst
means a catalyst having excellent curability and excellent
20 storage stability at ordinary temperature for exhibiting
its catalytic activity at an appropriate temperature or
higher. For example, JP-A-8-295,721 discloses that a
tetra-substituted phosphonium tetra-substituted borate in
which the substituents on boron have a specific structure
25 has both excellent curability and excellent storage

stability at ordinary temperature. The tetra-substituted phosphonium tetra-substituted borate exhibits its catalytic activity upon dissociation of the ionic bond between the anion portion and the cation portion, so that the temperature at which the catalytic activity is exhibited can be varied by changing the temperature at which the bond is dissociated. When the substituents on boron have a specific structure, the ionic bond comes to have an appropriate bond-strength and exhibits no activity at ordinary temperature but is dissociated at the curing temperature to rapidly exhibit activity. Therefore, excellent curability and excellent storage stability, namely latency, is developed. The field in which such a latent catalyst takes an important part includes an epoxy resin molding material for encapsulating a semiconductor such as IC, LSI or the like. As the catalyst which has heretofore been used, there are imidazoles, diazabicycloalkenes, triarylphosphines and the like; however, these catalysts act even at relatively low temperatures, so that molding materials in which these catalysts are used are inferior in storage stability at ordinary temperature. Therefore, when these molding materials are stored at ordinary temperature, such troubles arise that incomplete filling results from the lowering of flow property during molding, gold wire in IC chips is broken to cause conduction failure, and the like. Therefore, it has been essential to refrigerate the epoxy resin molding material for encapsulating a semiconductor (referred to hereinafter

as the encapsulating material in some cases) when it is transported and stored. Moreover, recently, the performance required for IC as to the moisture resistance reliability has become strict more and more. For example, 5 JP-A-7-242,683 mentions tetra-substituted phosphonium tetra-substituted borates in which phenoxy groups or the like are bonded to the phosphorus atom, namely P-O-C bonds are formed, and it discloses that the borates are effective as a catalyst enabling the encapsulating material to 10 develop the storage stability at ordinary temperature; however, these tetra-substituted phosphonium tetra-substituted borates are easily hydrolyzed to produce phosphoric acid and there is a fear that the moisture resistance reliability may be remarkably deteriorated.

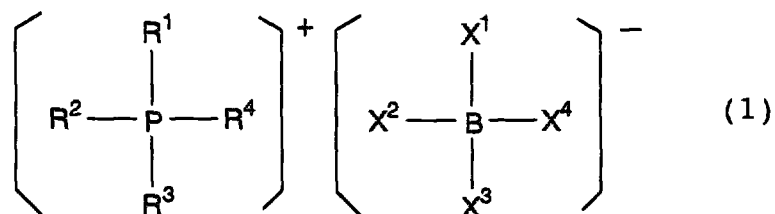
15 SUMMARY OF THE INVENTION

This invention provides a latent catalyst having extremely excellent moisture resistance reliability, curability and storage stability at ordinary temperature; a thermosetting resin composition comprising the same; an 20 epoxy resin molding material for encapsulating a semiconductor responding to insertion mounting and surface mounting which molding material comprises the above latent catalyst and has excellent moisture resistance reliability, storage stability at ordinary temperature and moldability; 25 and a semiconductor device in which the thermosetting molding material is used.

The present inventors have diligently repeated

research for solving the above-mentioned problems, and as a result of their examination of a relation between the moisture resistance reliability of the latent catalyst and the structure of a substituent bonded to the boron atom of the tetra-substituted phosphonium tetra-substituted borate described in JP-A-8-295,721 which is a patent application previously filed by the present inventors, they have found that a certain electric activity exhibited in water by a proton donor from which the substituent bonded to the boron atom results is closely connected with the moisture resistance reliability. That is to say, it has been clarified that when the electrical conductivity of the extraction water of the proton donor which is described in detail hereinafter is low, extremely excellent moisture resistance reliability is developed. Based on the above knowledge, this invention has been completed. That is to say, this invention provides the following:

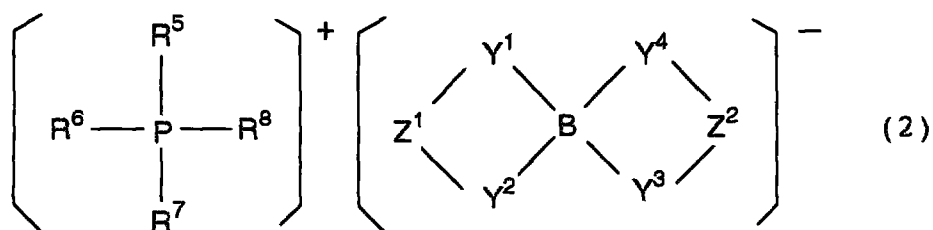
- (1) a latent catalyst composed of a phosphonium borate represented by the general formula (1) and a thermo-setting resin composition comprising the catalyst:



wherein R^1 , R^2 , R^3 and R^4 may be the same as or different from one another and each is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a

monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond; X^1 , X^2 , X^3 and X^4 may be the same as or different from one another and at least one of them is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton and each of the others is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group; and each of the above proton donors satisfies the condition that when 1 g of each proton donor is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus obtained becomes not more than 1,000 $\mu\text{S}/\text{cm}$,

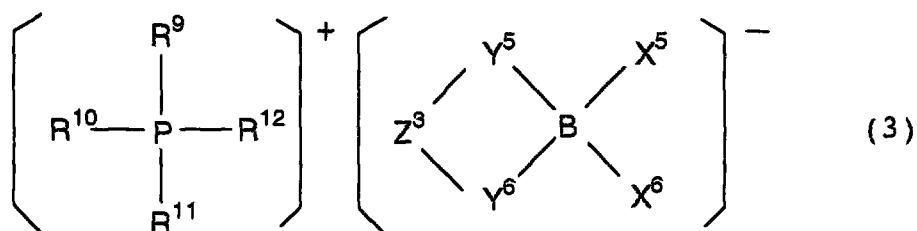
(2) a latent catalyst composed of a phosphonium borate represented by the general formula (2) and a thermosetting resin composition comprising the catalyst:



wherein R^5 , R^6 , R^7 and R^8 may be the same as or different from one another and each is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond; Z^1 is an organic group bonding to Y^1 and Y^2 ; Z^2 is an organic group bonding to Y^3 and Y^4 ; each

of Y^1 and Y^2 is a group formed when a monovalent, proton-donating substituent has liberated a proton and the substituents Y^1 and Y^2 in the same molecule are bonded to the boron atom to form a chelate structure; each of Y^3 and Y^4 is a group formed when a monovalent, proton-donating substituent has liberated a proton and the substituents Y^3 and Y^4 are bonded to the boron atom to form a chelate structure; Z^1 and Z^2 may be the same as or different from each other and also Y^1 , Y^2 , Y^3 and Y^4 may be the same as or different from one another; and $HY^1Z^1Y^2H$ and $HY^3Z^2Y^4H$ which are proton donors before the ligands of boron $Y^1Z^1Y^2$ and $Y^3Z^2Y^4$ are formed by liberation of the respective protons satisfy the condition that when 1 g of each of the proton donors is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus obtained becomes not more than 1,000 $\mu S/cm$,

(3) a latent catalyst composed of a phosphonium borate represented by the general formula (3) and a thermosetting resin composition comprising the catalyst:



wherein R^9 , R^{10} , R^{11} and R^{12} may be the same as or different from one another and each is a monovalent, organic group

having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond; Z^3 is an organic group bonding to the substituents Y^5 and Y^6 ; Y^5 and Y^6 may be the same as or different from each other and each is a group formed when a monovalent proton-donating substituent has liberated a proton and the substituents Y^5 and Y^6 in the same molecule are bonded to the boron atom to form a chelate structure; X^5 and X^6 may be the same as or different from each other and each is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton, or a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group; and $HY^5Z^3Y^6H$ which is a proton donor before the ligand of boron $Y^5Z^3Y^6$ is formed by liberation of the protons and HX^5 and HX^6 which are proton donors in the case where each of X^5 and X^6 is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton satisfy the condition that when 1 g of each of the proton donors is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus obtained becomes not more than 1,000 $\mu S/cm$,

(4) a latent catalyst having a structure wherein a phosphonium borate consisting of a monovalent cation portion in which four groups are bonded to the phosphorus

atom and a monovalent anion portion in which four groups are bonded to the boron atom is the recurring unit, at least two of which are connected through at least one of the four groups bonding to the boron atom (this type of latent catalyst is hereinafter referred to in some cases as the intermolecular reaction type latent catalyst) and a thermosetting resin composition comprising the above catalyst, provided that the group through which the recurring units are connected is a group formed when one proton donor has liberated at least two protons and the group may be composed of the same kind or different kinds; the groups bonding to the phosphorus atom may be the same as or different from one another and each thereof is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond; each of the groups which are bonded to the boron atoms but do not participate in the connection of the recurring units is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton, or a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and the above groups may be the same as or different from one another; and the proton donors from which the groups bonding to the boron atom result satisfy the condition that when 1 g of each of the proton donors is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20

hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus obtained becomes not more than 1,000 $\mu\text{S}/\text{cm}$, and

(5) An epoxy resin molding material comprising as the essential components (A) an epoxy resin, (B) a phenolic resin, (C) at least one latent catalyst selected from the latent catalysts defined in the above items (1) to (4) and (D) an inorganic filler, wherein the equivalent ratio between the epoxy group of the total epoxy resin and the phenolic hydroxyl group of the total phenolic resin is 0.5 to 2 and the amount of the inorganic filler (D) compounded is 200 to 2,400 parts by weight per 100 parts by weight of a total amount of the total epoxy resin and the total phenolic resin; and a semiconductor device in which the epoxy resin molding material is used.

DETAILED DESCRIPTION OF THE INVENTION

R^1 , R^2 , R^3 and R^4 in the general formula (1); R^5 , R^6 , R^7 and R^8 in the general formula (2); R^9 , R^{10} , R^{11} and R^{12} in the general formula (3); and the groups bonding to the phosphorus atom in the intermolecular reaction type latent catalyst defined in the above item (4) may be the same as or different from one another and each thereof is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond. Such phosphonium groups include tetraphenylphosphonium group, tetratolylphosphonium group, tetraethylphenylphosphonium

group, tetramethoxyphenylphosphonium group, tetranaphthylphosphonium group, tetrabenzylphosphonium group, ethyltriphenylphosphonium group, n-butyltriphenylphosphonium group, 2-hydroxyethyltriphenylphosphonium group, trimethylphenylphosphonium group, methyldiethylphenylphosphonium group, methyldiallylphenylphosphonium group, tetra-n-butylphosphonium group and the like; but are not limited thereto.

The proton donors from which the groups and ligands on boron result satisfy the condition that when 1 g of each of the proton donors is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus obtained becomes not more than 1,000 $\mu\text{S}/\text{cm}$. The groups and ligands on boron referred to above mean X^1 , X^2 , X^3 and X^4 in the general formula (1); X^5 and X^6 in the general formula (3); the groups which do not participate in the connection of the recurring units of the intermolecular reaction type phosphonium borate and which are formed when a proton donor has liberated one proton; $Y^1Z^1Y^2$ and $Y^3Z^2Y^4$ in the general formula (2); $Y^5Z^3Y^6$ in the general formula (3); and the groups participating in the connection of the recurring units of the intermolecular reaction type latent catalyst. In addition, each of the groups and ligands on boron has the structural characteristics as stated below.

At least one of X^1 , X^2 , X^3 and X^4 in the general formula (1) is a group formed when a proton donor having at

least one proton capable of being liberated out of the molecule has liberated one proton and each of the others is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group, and they may be the same as or different from one another. Each of X^5 and X^6 in the general formula (3) and the groups not participating in the connection of the recurring units of the intermolecular reaction type latent catalyst is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton or a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent aliphatic group and they may be the same as or different from one another. Such proton donors from which X^1 , X^2 , X^3 and X^4 in the general formula (1), X^5 and X^6 in the general formula (3) and the groups not participating in the connection of the recurring units of the intermolecular reaction type phosphonium borate result satisfy the condition that the electrical conductivity of the extraction water as defined herein becomes not more than 1,000 $\mu S/cm$. They include organic acids such as carboxylic acids, phenolic compounds and the like; isocyanuric acids; and benzo-triazoles and also include alcohols. Here, the phenolic compounds in this invention mean those in which at least one hydrogen bonded to the aromatic ring has been replaced with a hydroxyl group and include also hydroxyl group-substituted naphthalene and hydroxyl group-substituted other condensed polycyclic aromatics.

As the carboxylic acids, there are preferably mentioned aromatic carboxylic acids in which two carboxyl groups or a carboxyl group and a phenolic hydroxyl group are not present in the mutually adjacent positions, and
5 examples thereof include benzoic acid, m-hydroxybenzoic acid, 1-naphthoic acid, 2,6-naphthalenedicarboxylic acid and the like. In this case, the aromatic carboxylic acids include also those having other substituents than carboxyl group such as m-hydroxybenzoic acid and the like. However,
10 particularly preferable are substituted or unsubstituted benzoic acids and substituted or unsubstituted naphthoic acids. As the phenolic compounds, there are mentioned phenol, naphthol, p-phenylphenol, resorcin, 1,6-dihydroxynaphthalene, bisphenol A and the like. However,
15 particularly preferable are substituted or unsubstituted phenols and substituted or unsubstituted naphthols. As the alcohols, there can be mentioned, for example, methanol, butanol, 2-propen-1-ol and the like. Moreover, diverse proton donors, for example, carboxylic acid and alcohol or
20 phenol compound and isocyanuric acid, may be bonded to the same boron atom.

In the general formula (2), Z^1 is an organic group bonding to the substituents Y^1 and Y^2 . Each of Y^1 and Y^2 is a group formed when a monovalent proton-donating
25 substituent has liberated a proton and the substituents Y^1 and Y^2 in the same molecule are bonded to the boron atom to form a chelate structure. Z^2 is an organic group bonding to the substituents Y^3 and Y^4 . Each of Y^3 and Y^4 is a group

formed when a monovalent, proton-donating substituent has liberated a proton and the substituents Y^3 and Y^4 in the same molecule are bonded to the boron atom to form a chelate structure. Z^1 and Z^2 may be the same as or
5 different from each other and Y^1 , Y^2 , Y^3 and Y^4 may be the same as or different from one another. In the general formula (3), Z^3 is an organic group bonding to the substituents Y^5 and Y^6 . Each of Y^5 and Y^6 is a group formed when a monovalent proton-donating substituent has liberated a
10 proton, and the substituents Y^5 and Y^6 in the same molecule are bonded to the boron atom to form a chelate structure. The group through which the recurring units of the intermolecular reaction type latent catalyst are connected is a group formed when one proton donor has liberated two or
15 more protons and the group may be composed of the same kind or different kinds.

Examples of the proton donors from which $Y^1Z^1Y^2$ and $Y^3Z^2Y^4$ in the general formula (2), $Y^5Z^3Y^6$ in the general formula (3) and the group through which the recurring units
20 of the intermolecular reaction type latent catalyst are connected result, include organic acids such as carboxylic acids, phenolic compounds and the like and also include polyhydric alcohols and the like.

As such carboxylic acids and phenolic compounds,
25 preferable are aromatic carboxylic acids and phenolic compounds which have at least two substituents selected from the group consisting of carboxyl group and phenolic hydroxyl group and in which two carboxyl groups or a

carboxyl group and a phenolic hydroxyl group are not present in the mutually adjacent positions, and examples thereof include m-hydroxybenzoic acid, 3-hydroxy-1-naphthoic acid, isophthalic acid, 1,6-naphthalene-
5 dicarboxylic acid, catechol, resorcin, 2,3-dihydroxy-naphthalene, 2,2'-biphenol, bisphenol A, bisphenol S, 2,2'-methylene-bis(4-methylphenol) and the like. Among them, particularly preferable are dihydroxybenzene, dihydroxy-naphthalene, bisphenols and biphenols. As the polyhydric
10 alcohols, there can be mentioned 1,2-cyclohexanediol, 1,2-propanediol and the like. Furthermore, divergent proton donors, for example, a carboxylic acid and an alcohol, may be bonded to the same boron atom.

The intermolecular reaction type latent catalyst
15 in the above item (4) is a polymolecular type phosphonium borate in which the number of moles of the phosphorus atom of the phosphonium group on the cationic side is equal to the number of moles of the boron atom of the borate on the anionic side.

20 The cationic side is composed of a phosphonium, each of the substituents of which is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and in which the phosphorus atom and each substituent form a P-C bond, and every
25 phosphonium group thereof forms an ionic pair with the boron anion (borate) on the anionic side. On the anionic side, at least one of the four groups on boron is bonded to at least one other boron through the conjugate base of a

divalent or more multivalent proton donor, whereby a structure in which at least two recurring units which have been subjected to intermolecular reaction on the anionic side are connected, is formed. The number of the recurring
5 units is not limited, and the conjugate bases of the divalent or more multivalent proton donors which have participated in the connection may be the same as or different from one another. Each of the groups on boron which do not participate in the connection of the recurring
10 units is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton or a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group, and they may be the same as or
15 different from one another. The recurring unit means a pair of tetra-substituted phosphonium tetra-substituted borate.

The pressure cooker vessel used in this invention is a vessel having an internal volume of about 70 cc and
20 having a double structure in which the inside is made of Teflon and the outside is of stainless steel, which vessel can maintain the content in the pressurized state in order to keep excellent closeness during the pressure cooker treatment and in which vessel substantially no impurity is
25 dissolved out of the internal Teflon vessel during the pressure cooker treatment. The electrical conductivity of pure water used in this invention is not more than 5 $\mu\text{S}/\text{cm}$.

Moreover, the electrical conductivity of the

extraction water in this invention is a value obtained by taking out the content of the pressure cooker vessel after the pressure cooker treatment at 125°C for 20 hours, subjecting it to centrifugation and measuring the
5 electrical conductivity of the extraction water thus obtained by a conductivity meter (Model ES-14 manufactured by HORIBA, LTD.).

The latent catalyst of this invention selected from the group consisting of the latent catalysts
10 represented by the general formulas (1), (2) and (3) and the intermolecular reaction type latent catalyst defined in the above item (4) has a possibility of gradually generating a proton donor by contact of the group and ligand on boron with water when the moisture resistance reliability
15 is evaluated. In addition, there is a fear that this proton donor adversely affects the resin-encapsulated electric and electronic parts when the moisture resistance reliability is evaluated. However, the present inventors have found that the proton donor which can be generated
20 from the latent catalyst of this invention, that is, the proton donor satisfying the condition that the electrical conductivity of the extraction water obtained under the above-mentioned conditions is not more than 1,000 $\mu\text{S}/\text{cm}$, does not have such an adverse effect, and the latent
25 catalyst of this invention is extremely excellent in moisture resistance reliability.

The detailed reason why the proton donor having the electrical conductivity of the extraction water not

more than a specific value does not adversely affect the moisture resistance reliability as discussed above has not been clarified, but the electrical conductivity of the extraction water depends generally upon the solubility of the proton donor in water, the pKa of the proton donor and the mobility of the dissociated proton donor in water and reflects the behavior of the proton donor in the evaluation of the moisture resistance reliability. It can also be said that this value being large means that the proton donor tends to have some chemical action on the internal electric and electronic parts. The present inventors have examined the correlation between the electrical conductivity of the extraction water of the proton donor obtained under the above-mentioned conditions and the moisture resistance reliability to find that when the electrical conductivity of the extraction water is not more than 1,000 $\mu\text{S}/\text{cm}$, excellent moisture resistance reliability is developed and further to find a proton donor which develops a good moisture resistance reliability.

The total amount of the latent catalysts of this invention to be added to a thermosetting resin is 0.4 to 20 parts by weight per 100 parts by weight of the thermosetting resin. When the amount is less than 0.4 part by weight, it is too small to exert a sufficient catalytic effect, and when the amount exceeds 20 parts by weight, such inconveniences that the flow property is lowered and the like are caused in some cases.

The thermosetting resin to be contained in the

thermosetting resin composition of this invention includes epoxy resins and maleimide resins, and also includes such resins that the reactive monomers are cyanates, isocyanates or acrylates; alkenyl resins; and alkynyl resins. In this
5 invention, the term "thermosetting resin" should be interpreted to mean all resin systems whose thermal curing can be accelerated by use of the latent catalyst of this invention. Among them, the most preferable thermosetting resins are epoxy resins and maleimide resins; however, it
10 is not objectionable to use the above-mentioned various thermosetting resins alone or in combination of two or more. Specific examples of the epoxy resins and maleimide resins are mentioned below.

As the epoxy resin in this invention, there can
15 be mentioned bisphenol A type epoxy resins, bisphenol F type epoxy resins, brominated bisphenol type epoxy resins, biphenyl type epoxy resins, phenolic novolac type epoxy resins, cresol novolac type epoxy resins, alicyclic epoxy resins, glycidyl ester type epoxy resins, glycidylamine
20 type epoxy resins, naphthalene type epoxy resins, glycidyl ether compounds of resins synthesized by condensation of naphthol or the like with a carbonyl compound, stilbene type epoxy resins, 4,4'-bis(1,2-epoxyethyl)diphenyl ether, 4,4'-bis(1,2-epoxyethyl)biphenyl, glycidyl ether compounds
25 of phenolic resins obtained by reacting dicyclopentadiene with a phenol, and further, glycidyl ether compounds of monocyclic resorcin, catechol and the like; etc. These can be used alone or in combination of two or more.

In this invention, any curing agent which can react with the epoxy group to cause curing reaction can be used, if necessary. Specifically, as organic diamines and polyamines, there are mentioned straight chain aliphatic amines such as diethylenetriamine and triethylenetetramine; aliphatic amines such as N-aminoethylpiperazine and bis(4-aminocyclohexyl)methane; aromatic amines such as m-xylenediamine and diaminodiphenylmethane; dicyandiamide; guanidines; various polyamides; and modified polyamines.

As examples of acid anhydrides, there are phthalic anhydride, trimellitic anhydride, tetrahydrophthalic anhydride and the like. Moreover, examples of phenols include phenolic resins and bisphenols which are co-condensation products of phenols with aldehydes or ketones; and phenolaralkyl resins which are co-condensation products of phenols with dimethoxy-p-xylene. Monocyclic resorcin, catechol and the like can be also used if they cause curing reaction. Since the definition of "phenol" is generally an aromatic compound in which the hydrogen atom bonded to the aromatic ring has been replaced by a hydroxyl group, the phenols include also co-condensation products of carbonyl compounds with hydroxyl group-containing compounds resulting from condensed polycyclic aromatics such as naphthol, and the like.

As the maleimide resins in this invention, there can be mentioned, for example, maleimides such as N,N'-m-phenylenebismaleimide, N,N'-m-toluylenebismaleimide, N,N'-4,4'-biphenylenebismaleimide, N,N'-4,4'-[3,3'-dimethyl-

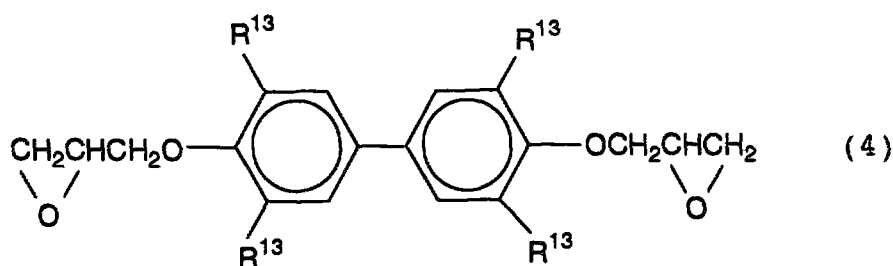
biphenylene]bismaleimide, N,N'-4,4'-[3,3'-dimethyldiphenyl-
methane]bismaleimide, N,N'-4,4'-diphenylmethane-
bismaleimide, N,N'-4,4'-diphenyletherbismaleimide, N,N'-
4,4'-diphenylsulfonebismaleimide, 2,2-bis(4-(4-maleimido-
5 phenoxy)phenyl)propane, 2,2-bis(4-(4-maleimidophenoxy)-
phenyl)hexafluoropropane, 2,2-bis(4-(4-maleimidophenoxy)-
phenyl)sulfone and the like; products obtained by reacting
these maleimides with amines by Michael addition; products
obtained by addition reaction of the double bond of
10 maleimides with the unsaturated bond of unsaturated group-
containing compounds; and the like. These can be used
alone or in combination of two or more. In addition, these
can contain alkenylphenols, if necessary.

The thermosetting resin composition of this
15 invention can, if necessary, contain inorganic fillers such
as alumina, fused silica, crystalline silica, clay, talc
and the like; various reinforcing agents such as glass
cloth and the like; and additives such as releasing agents,
flame retardants, coupling agents, coloring agents,
20 antioxidants, surface active agents, conventionally known
curing catalysts and the like.

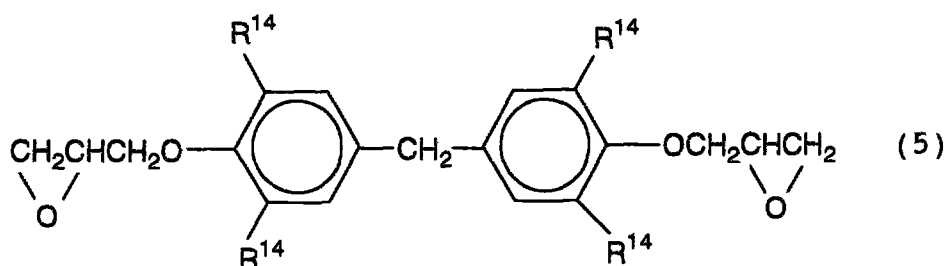
In the epoxy resin molding material of this
invention, the epoxy resin contained as the component (A)
in addition to the latent catalyst of this invention which
25 is the component (C), refers to all those monomers,
oligomers and polymers which have at least two epoxy groups
in one molecule. There are mentioned, for example,
biphenyl type epoxy resins, bisphenol type epoxy resins,

stilbene type epoxy resins, o-cresol novolac type epoxy resins, phenolic novolac type epoxy resins, triphenol-methane type epoxy resins, alkyl-modified triphenolmethane type epoxy resins, triazine nucleus-containing epoxy resins, dicyclopentadiene-modified phenol type epoxy resins and the like. These may be used alone or in admixture. Among these epoxy resins, preferable are crystalline epoxy resins having a melting point of 50-150°C. Such crystalline epoxy resins have a stiff structure such as biphenyl skeleton, bisphenol skeleton, stilbene skeleton or the like and have a relatively low molecular weight, and hence, show crystallizability. The crystalline epoxy resin is a solid which is crystallized at ordinary temperature, but rapidly melts in a temperature zone not lower than the melting point to be converted to a low viscosity liquid. The melting point of the crystalline epoxy resin means the temperature of the top of the endothermic peak of crystal fusion obtained by a differential scanning calorimeter when the temperature is elevated from ordinary temperature at a temperature-elevating rate of 5°C/min.

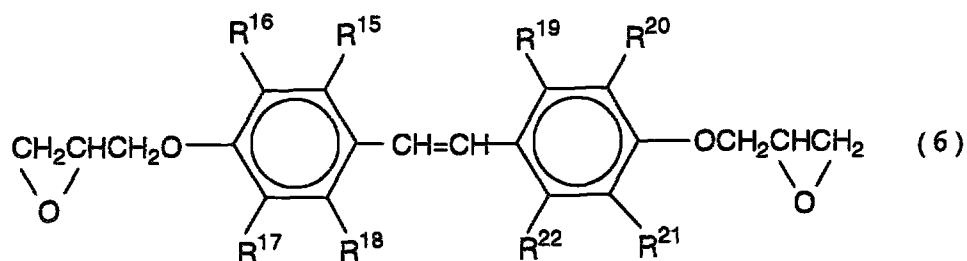
As the crystalline epoxy resin which satisfies the above conditions, particularly preferable is at least one member selected from the epoxy resins represented by the general formulas (4) and (5) or a mixture of a stilbene type epoxy resin represented by the general formula (6) with a stilbene type epoxy resin represented by the general formula (7).



wherein each R^{13} is an atom or a group selected from the group consisting of hydrogen atom, chain or cyclic alkyl groups having 1 to 6 carbon atoms, phenyl group and halogen atoms and the R^{13} atoms or groups may be the same as or different from one another.

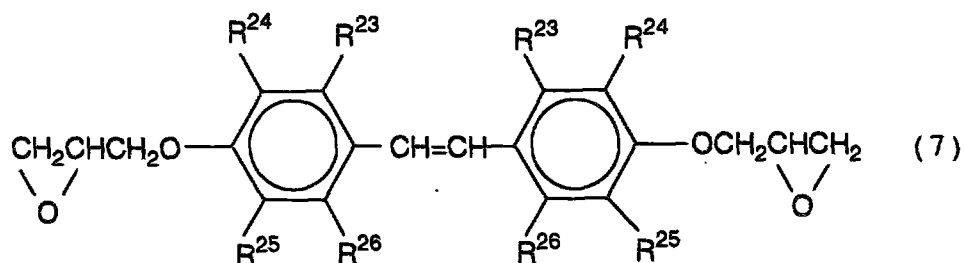


wherein each R^{14} is a group or an atom selected from the group consisting of hydrogen atom, chain or cyclic alkyl groups having 1 to 6 carbon atoms, phenyl group and halogen atoms, and the R^{14} groups or atoms may be the same as or different from one another.



wherein each of R^{15} to R^{22} represents independently a group or an atom selected from the group consisting of hydrogen atom, chain or cyclic alkyl groups having 1 to 6 carbon

atoms and halogen atoms, provided that the two aryl groups bonded to the carbon-carbon double bond are different from each other.



5 wherein each of R^{23} to R^{26} represents independently a group or an atom selected from the group consisting of hydrogen atom, chain or cyclic alkyl groups having 1 to 6 carbon atoms and halogen atoms, provided that the two aryl groups bonded to the carbon-carbon double bond are the same as
10 each other.

As the substituents R^{13} and R^{14} , there are mentioned, for example, methyl group, ethyl group, propyl group, butyl group, cyclohexyl group, phenyl group, chlorine atom, bromine atom and the like, and particularly
15 preferable is methyl group.

As the substituents R^{15} to R^{26} , there are mentioned, for example, hydrogen atom, methyl group, ethyl group, propyl group, butyl group, amyl group, hexyl group (including the respective isomers), cyclohexyl group,
20 chlorine atom, bromine atom and the like, and particularly preferable are methyl group, ethyl group, propyl group and butyl group when it is taken into consideration that the melt viscosity of the epoxy resin is low.

With regard to a mixture of the stilbene type

epoxy resin represented by the general formula (6) with the stilbene type epoxy resin represented by the general formula (7), both the stilbene type epoxy resins represented by the general formulas (6) and (7) include
5 those having various structures depending upon the kind of substituent and the like, and each of the stilbene type epoxy resins represented by the general formulas (6) and (7) may be that having one kind structure or a mixture of those having different structures.

10 The mixing of the stilbene type epoxy resin represented by the general formula (6) with the stilbene type epoxy resin represented by the general formula (7) aims at lowering the melting point by mixing both the compounds and the mixing method is not limited. There are,
15 for example, a method in which stilbene type phenols which are the starting materials of the stilbene type epoxy resins are previously mixed before the glycidyl etherification of them, a method in which both the stilbene type epoxy resins are mixed in the molten state, and the like.
20 However, in any case, the melting point is adjusted to 50-150°C.

 As the stilbene type epoxy resin represented by the general formula (6), particularly preferable are glycidyl etherification products of 5-tertiary butyl-4,4'-
25 dihydroxy-2,3',5'-trimethylstilbene and 3-tertiary butyl-4,4'-dihydroxy-3',5,5'-trimethylstilbene from the viewpoint of easy availability, performance and starting material cost.

As the stilbene type epoxy resin represented by the general formula (7), particularly preferable are glycidyl etherification products of 4,4'-dihydroxy-3,3',5,5'-tetramethylstilbene, 4,4'-dihydroxy-3,3'-
5 ditertiary butyl-6,6'-dimethylstilbene, 4,4'-dihydroxy-3,3'-ditertiary butyl-5,5'-dimethylstilbene from the viewpoint of performance and starting material cost.

The phenolic resin used as the component (B) of the epoxy resin molding material of this invention refers
10 to all those monomers, oligomers and polymers which have at least two phenolic hydroxyl groups in one molecule, and includes, for example, phenolic novolacs, cresol novolacs, p-xylylene-modified phenolic resins, p-xylylene-m-xylylene-modified phenolic resins, terpene-modified phenolic resins,
15 dicyclopentadiene-modified phenolic resins and the like. These may be used alone or in admixture. These phenolic resins can be used without being limited by molecular weight, softening point, hydroxyl group equivalent and the like.

20 Among these phenolic resins, particularly preferable are phenolaralkyl resins, because the water absorption of a molded article is small owing to little hydroxyl group in the molecule, the reactivity in the curing reaction is good owing to an appropriate mobility of
25 the molecule and it is possible to make the viscosity low.

The equivalent ratio between the epoxy group of the total epoxy resin and the phenolic hydroxyl group of the total phenolic resin used in the epoxy resin molding

material of this invention is 0.5 to 2, preferably 0.7 to 1.5. When the equivalent ratio is outside the range of 0.5 to 2, the curability, moisture resistance and the like are lowered, so that the equivalent ratios outside the above
5 range are not desirable.

The kind of the inorganic filler used in the epoxy resin molding material of this invention is not limited, and there can be used those which are generally used in the encapsulating materials. There are mentioned,
10 for example, fused crushed silica powder, fused spherical silica powder, crystalline silica powder, secondary agglomeration silica powder, alumina, titanium white, aluminum hydroxide, talc, clay, glass fiber and the like, and particularly preferable is fused spherical silica
15 powder. The shape is preferably as close to true sphere as possible, and the amount of filler packed can be made large by mixing particles having different sizes.

The amount of the inorganic filler compounded is 200 to 2,400 parts by weight per 100 parts by weight of a
20 total amount of the total epoxy resin and the total phenolic resin. When the amount is less than 200 parts by weight, there is a fear that the reinforcing effect of the inorganic filler may not be sufficiently developed, and when the amount exceeds 2,400 parts by weight, there is a
25 fear that the flow property of the resin composition may be deteriorated and incomplete filling and the like may be caused during molding, so that the amounts outside the above range are not desirable. In particular, when the

amount of the inorganic filler compounded is 250 to 1,400 parts by weight per 100 parts by weight of a total amount of the total epoxy resin and the total phenolic resin, the moisture absorption of the cured product of the resin composition becomes low, and the solder crack can be prevented from being caused, and further, the viscosity of the resin composition when melted becomes low, so that there is no fear that wire sweep can be caused in the interior of a semiconductor device. Therefore, said amount range is more preferable. Furthermore, it is preferable that the inorganic filler is previously mixed sufficiently.

The epoxy resin molding material of this invention can be compounded with, if necessary, various additives, for example, coupling agents such as γ -glycidoxypropyltrimethoxysilane and the like; coloring agents such as carbon black and the like; flame retardants such as brominated epoxy resins, antimony oxide, phosphorus compounds and the like; low stress components such as silicone oil, silicone rubber and the like; releasing agents such as natural wax, synthetic waxes, higher fatty acids, metal salts of higher fatty acids, paraffins and the like; antioxidants; etc., in addition to the components (A) to (D), and no troubles are caused even when the above additives are used in combination with other known catalysts such as triphenylphosphine, 1,8-diazabicyclo-(5,4,0)undecene-7, 2-methylimidazole and the like in such an amount that the characteristics of the latent catalyst of this invention are not deteriorated.

The epoxy resin molding material of this invention is obtained by mixing the components (A) to (D), the above-mentioned additives and the like at ordinary temperature using a mixer, kneading the resulting mixture
5 in a kneader such as a roll, an extruder or the like, cooling the kneaded mixture and then pulverizing the same.

In order to encapsulate an electronic part such as a semiconductor or the like with the epoxy resin molding material of this invention to produce a semiconductor
10 device, it is sufficient to cure and mold the molding material by a molding method such as transfer molding, compression molding, injection molding or the like.

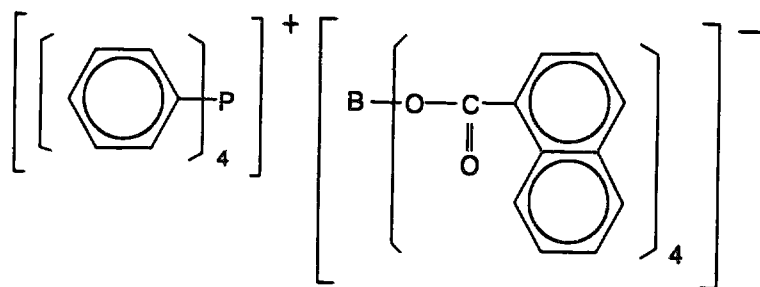
DESCRIPTION OF PREFERRED EMBODIMENTS

Examples are shown below to explain this inven-
15 tion in more detail; however, this invention should not be construed to be limited to the Examples.

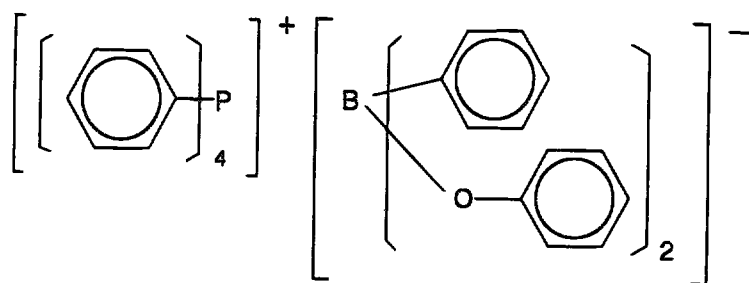
1. Examples relating to latent catalysts and thermo-setting resin compositions comprising the catalysts
Compounds 1 to 4 and 7 to 14

20 The structures of Compounds 1 to 4 and 7 to 14 used as catalysts (curing accelerators) in the Examples and Comparative Examples are shown below by chemical structural formulas.

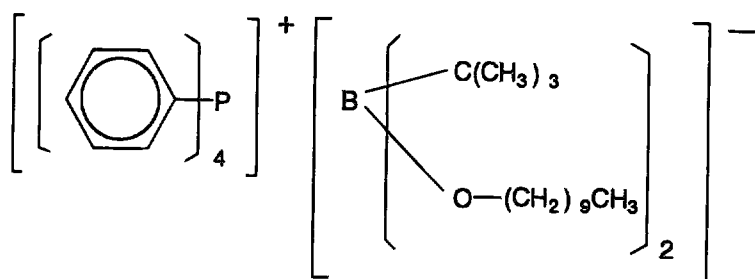
Compound 1



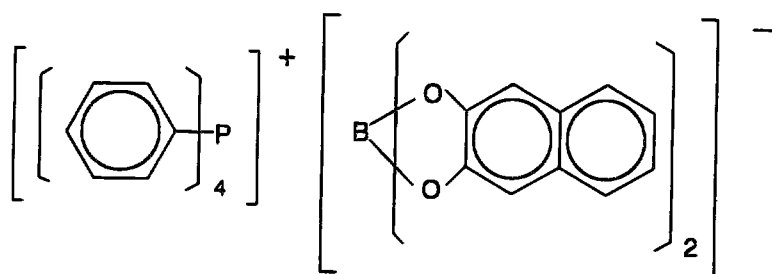
Compound 2



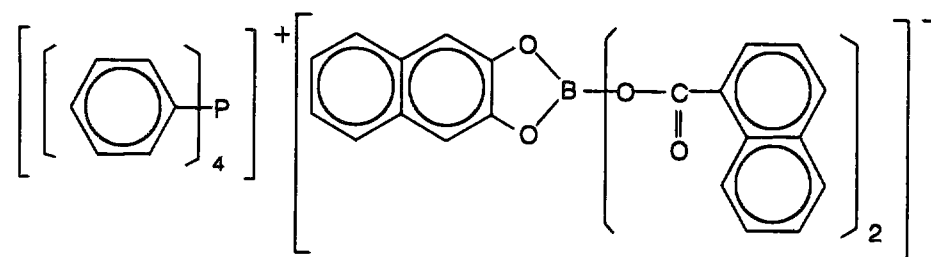
5 Compound 3



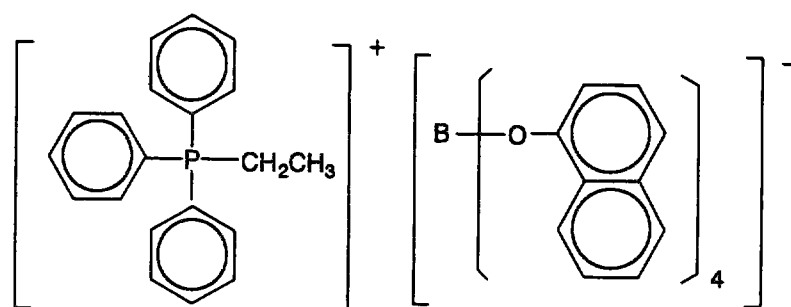
Compound 4



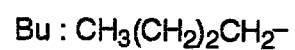
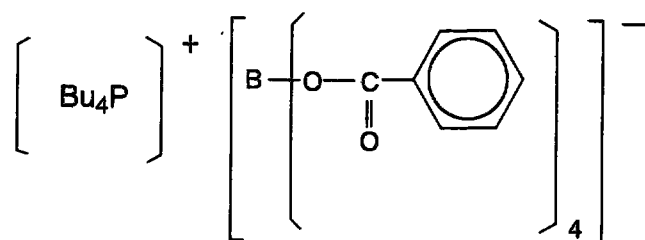
Compound 7



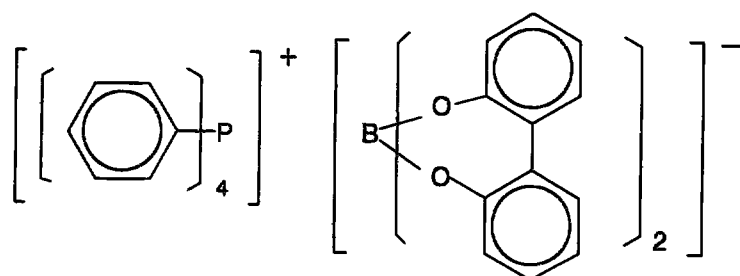
Compound 8



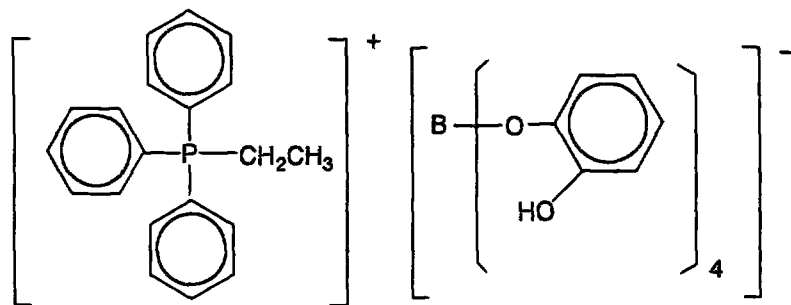
5 Compound 9



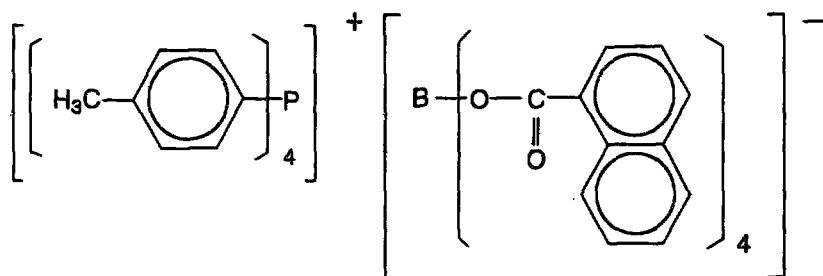
Compound 10



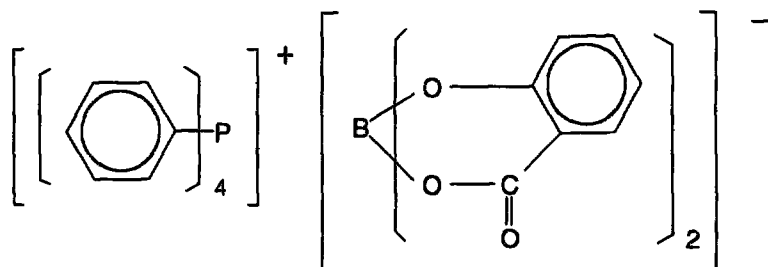
Compound 11



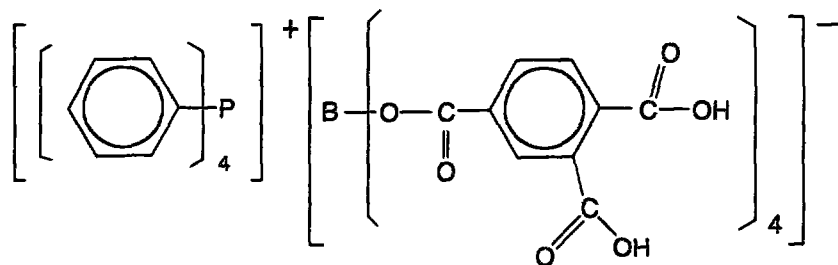
Compound 12



5 Compound 13



Compound 14



Compounds 5 and 6

Compounds 5 and 6 are intermolecular reaction type latent catalysts corresponding to the above item (4). That is to say, they are polymolecular type phosphonium borates in which the number of moles of phosphorus atom of the phosphonium group on the cationic side is equal to the number of moles of boron atom of the borate on the anionic side.

a) Compound 5

10 The cationic side is a tetraphenylphosphonium group and each of the phosphonium groups forms an ionic pair with the boron anion on the anionic side. The anionic side has a recurring structure in which each of the four groups on boron is substituted by one of the two
15 carboxylates of the conjugate base of isophthalic acid (isophthalate) and is further bonded to the boron atom of another molecule through the other carboxylate of the conjugate base of isophthalic acid. In this case, the recurring structure becomes a structure in which the boron
20 atom is reacted with the isophthalate in a molar ratio of 1 : 2 on average.

b) Compound 6

The cationic side is a tetraphenylphosphonium group and each of the phosphonium groups forms an ionic
25 pair with the boron anion on the anionic side. The anionic side has a recurring structure in which each of the four groups on boron is bonded to one of the two phenoxides of

the conjugate base of bisphenol A and two other phenoxides on average are bonded to the boron of another molecule. In this case, the recurring structure becomes a structure in which the boron atom is reacted with the bisphenol A in a molar ratio of 1 : 3 on average.

The names of proton donors from which the groups and ligands on boron result and the electrical conductivities of the extraction water obtained by mixing 1 g of one of the proton donors with 50 g of purified water and then subjecting the resulting mixture to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel are collectively shown in Table 1. The proton donor corresponding to Compound 13 is an aromatic carboxylic acid having one carboxyl group in one molecule and one hydroxyl group in a position adjacent thereto, and the proton donor corresponding to Compound 14 is an aromatic carboxylic acid having two carboxyl groups in the mutually adjacent positions in the molecule.

(1) Evaluation with epoxy/(maleimide)/phenolic resin curing system

One of the various catalysts was incorporated into a thermosetting resin composition as shown in Table 2 and flow property, curability, storage stability and moisture resistance reliability were evaluated by the procedures stated below.

Specific evaluation methods are described below.

(i) Spiral flow

Using a mold for measuring a spiral flow according to EMMI-I-66, measurement was effected at a mold temperature of 175°C at an injection pressure of 70 kg/cm² for a curing time of 2 minutes. The spiral flow is a parameter of flow property and the larger the value, the better the fluidity.

(ii) Curing torque

Using a curelastometer (JSR CURELASTOMETER Model IVPS manufactured by Orientech Co., Ltd.), the torque after 90 seconds at 175°C was determined. The torque in the curelastometer is a parameter of curability and the larger the value, the better the curability.

(iii) Residual flow percentage

A sample was preserved at 25°C for 30 days and thereafter subjected again to measurement of spiral flow, after which the percentage of the value obtained based on the initial spiral flow just after the preparation of the sample was determined by the following equation:

$$\text{Residual flow percentage (\%)} = (\text{spiral flow value after storage} / \text{initial spiral flow value}) \times 100$$

The larger the residual flow percentage, the better the storage stability.

(iv) Moisture resistance reliability

A 16-pin DIP was encapsulated with a resin composition obtained by mixing and kneading various components, and thereto was applied a voltage of 20 V in water vapor at 125°C at a relative humidity of 100% for the

predetermined period of time, after which conduction failure was checked. The time until the failure took place in a half of the packages evaluated was determined as a PCBT failure time. Incidentally, the evaluation time was
5 500 hours at longest and in the case where the number of failed packages at that time was less than half, the failure time was shown as "more than 500 hours". The longer this time, the better the moisture resistance reliability.

10 Example 1

67 Parts by weight (hereinafter abbreviated to parts) of o-cresol novolac type epoxy (EOCN-1020-65 manufactured by NIPPON KAYAKU CO., LTD.), 33 parts of a phenolic novolac (PR-51470 manufactured by SUMITOMO DUREZ
15 CO., LTD.), 4.3 parts of Compound 1 as a catalyst, 300 parts of fused silica and 2 parts of carnauba wax were mixed and then roll-milled at 90°C for 8 minutes to obtain a molding material. The spiral flow of this molding material was 70 cm and the curing torque thereof was 78 kgf·cm. The
20 residual flow percentage after 30 days at 25°C was 99%. Also, the PCBT failure time was more than 500 hours.

Example 2

52 Parts of a biphenol type glycidyl ether epoxy (YX-4000H manufactured by Yuka Shell Epoxy Co., Ltd.), 48
25 parts of a p-xylene type phenolic resin (XL-225 manufactured by Mitsui Toatsu Chemicals, Inc.), 2.9 parts of

Compound 2 as a catalyst, 800 parts of fused silica and 3 parts of carnauba wax were mixed and then roll-milled at 90°C for 8 minutes to obtain a molding material. The spiral flow of this molding material was 90 cm and the curing torque thereof was 83 kgf·cm. The spiral flow residue after 30 days at 25°C was 93%. Moreover, the PCBT failure time was more than 500 hours.

Examples 3 to 11 and Comparative Examples 1 and 2

According to the composition shown in Table 2, the components were mixed and a molding mixture was prepared and evaluated in the same manner as in Examples 1 and 2. The results obtained are collectively shown in Table 2, provided that in Examples 5 and 9, 70 parts of 2,2-bis(4-(4-maleimidophenoxy)phenyl)propane (Bismaleimide MB-8000 manufactured by Mitsubishi Yuka K. K.) was further mixed as a resin component in addition to EOCN-1020-65 and PR-51470 according to the composition shown in Table 2 and a molding material was prepared and evaluated in the same manner as in Example 1.

The PCBT failure time in each of Examples 1 to 11 was more than 500 hours. On the other hand, the PCBT failure time in each of Comparative Examples 1 and 2 was much shorter than 500 hours. From this fact, it is clear that the thermosetting resin compositions containing the latent catalyst of this invention exhibit extremely excellent moisture resistance reliability. Moreover, from the curing torques and residual flow percentages in

Examples 1 to 11 and Comparative Examples 1 and 2, it is clear that the latent catalysts of this invention exhibit excellent curability and storage stability at ordinary temperature.

5 (2) Evaluation with epoxy/amine curing system

Example 12

In 100 parts of a mixed solvent of N,N-dimethylformamide and methyl ethyl ketone (1 : 1) were dissolved 95 parts of a bisphenol A type epoxy resin (EP-1001 manufactured by Yuka Shell Epoxy K. K.), 4 parts of diamino-
10 diphenylmethane, 1 part of dicyandiamide and 3.3 parts of Compound 1 to prepare a varnish. A 100- μ glass cloth was impregnated with this varnish and then dried at 150°C for 4 minutes to obtain a prepreg. Sixteen sheets of this
15 prepreg were piled one on another and a copper foil having a thickness of 35 μ was put on the outsides of the resulting assembly, after which the resulting assembly was sandwiched in between two sheets of a stainless steel plate and pressed at 40 kg/cm² at 170°C for 50 minutes to obtain a
20 double-copper-clad laminate having a thickness of 1.6 mm. The double-copper-clad laminate obtained was subjected, if necessary, to etching and then to measurement of glass transition temperature at a temperature-elevating rate of 5°C/min in a dynamic viscoelasticity measuring apparatus.
25 Furthermore, the evaluation of prepreg storage stability was conducted by removing the resin component from the prepreg, measuring the initial gel time (abbreviated to GT)

at 170°C and then the gel time after storage at 40°C at 35% RH for 7 days, and calculating the residual GT percentage according to the following equation:

$$\text{Residual GT percentage (\%)} = (\text{GT (sec) after 7 days at 40}^\circ\text{C at 35\% RH} / \text{initial GT (sec)}) \times 100.$$

The larger the residual gel time percentage, the better the storage stability.

Examples 13 to 17 and Comparative Example 3

According to the composition shown in Table 3, the components were mixed and a sample was prepared and evaluated in the same manner as in Example 12. The results obtained are shown in Table 3.

(3) Evaluation with maleimide system

Example 18

In 100 parts of a mixed solvent of chloroform and N,N-dimethylformamide (1 : 1) were dissolved 100 parts of 2,2-bis(4-(4-maleimidophenoxy)phenyl)propane (BMI-80 manufactured by Keiai Kasei) and 3.1 parts of Compound 1 to prepare a varnish, and the varnish was rapidly vacuum-dried immediately after the preparation to remove the solvent, thereby obtaining a solid content. The initial gel time at 175°C and the gel time after storage at 40°C for 3 days of the solid content were measured and the residual gel time percentage was calculated by the following equation:

$$\text{Residual gel time percentage (\%)} = (\text{GT (sec) after 3 days at 40}^\circ\text{C} / \text{initial GT (sec)}) \times 100.$$

The larger the residual gel time percentage, the better the storage stability.

Examples 19 to 23 and Comparative Example 4

According to the composition shown in Table 4,
5 the components were mixed and a sample was prepared and evaluated in the same manner as in Example 18. The results obtained are shown in Table 4.

Table 1

Catalyst	Type ¹⁾	Corresponding proton donor	Electrical conductivity of extraction water of corresponding proton donor ($\mu\text{S}/\text{cm}$)
Compound 1	A	Naphthoic acid	121
Compound 2	A	Phenol	27
Compound 3	A	n-Decanol	5
Compound 4	B	2,3-Dihydroxy- naphthalene	33
Compound 5	D	Isophthalic acid	184
Compound 6	D	Bisphenol A	10
Compound 7	C	Naphthoic acid	121
		2,3-Dihydroxy- naphthalene	33
Compound 8	A	Naphthol	11
Compound 9	A	Benzoic acid	470
Compound 10	B	2,2'-Biphenol	19
Compound 11	A	Resorcin	9
Compound 12	A	Naphthoic acid	121
Compound 13	-	Salicylic acid	1356
Compound 14	-	Trimellitic acid	5904

Note: 1) A: Type represented by general formula (1) defined in Claim 1.
 B: Type represented by general formula (2) defined in Claim 2.
 C: Type represented by general formula (3) defined in Claim 3.
 D: Intermolecular reaction type defined in Claim 4.

Table 2

		Example 1	Example 2	Example 3	Example 4	Example 5	Example 6
	Catalyst species	Compound 1	Compound 2	Compound 3	Compound 4	Compound 5	Compound 6
	Proton donor species	Naphthoic acid	Phenol	n-Decanol	2,3-Dihydroxy-naphthalene	Isophthalic acid	Bisphenol A
Composition (part by weight)	Catalyst (Curing accelerator)	4.3	2.9	3.2	3.3	2.8	4
	EOCN-1020-65	67	-	67	-	20	-
	PR-51470	33	-	33	-	10	-
	YX4000H	-	52	-	52	-	52
	XL-225	-	48	-	48	-	48
	MB-8000	-	-	-	-	70	-
	Fused silica	300	800	300	800	300	800
	Carnauba wax	2	3	2	3	2	3
Curing torque (kgf·cm)		78	83	75	86	90	77
Spiral flow (cm)		70	90	72	100	81	94
Residual flow percentage (%)		99	93	89	90	96	90
Moisture resistance reliability evaluation		>500	>500	>500	>500	>500	>500

Table 2 (Cont'd)

		Example 7	Example 8	Example 9	Example 10	Example 11	Comp.Ex. 1	Comp.Ex. 2
	Catalyst species	Compound 8	Compound 9	Compound 10	Compound 11	Compound 12	Compound 13	Compound 14
	Proton donor species	Naphthol	Benzoic acid	2,2'-Biphenol	Resorcin	Naphthoic acid	Salicylic acid	Trimellitic acid
Composition (part by weight)	Catalyst (Curing accelerator)	4.1	3.1	3.5	3	3.8	3	4.9
	EOCN-1020-65	67	-	20	-	67	67	-
	PR-51470	33	-	10	-	33	33	-
	YX4000H	-	52	-	52	-	-	52
	XL-225	-	48	-	48	-	-	48
	MB-8000	-	-	70	-	-	-	-
	Fused silica	300	800	300	800	300	300	800
	Carnauba wax	2	3	2	3	2	2	3
Curing torque (kgf·cm)		81	88	79	83	84	90	90
Spiral flow (cm)		75	82	76	91	78	99	83
Residual flow percentage (%)		96	91	88	87	99	88	90
Moisture resistance reliability evaluation		>500	>500	>500	>500	>500	300	250

Table 3

		Example 12	Example 13	Example 14	Example 15	Example 16	Example 17	Comp.Ex. 3
	Catalyst species	Compound 1	Compound 8	Compound 9	Compound 4	Compound 11	Compound 6	2-Phenyl-4-methyl-imidazole
	Proton donor species	Naphthoic acid	Naphthol	Benzoic acid	2,3-Dihydroxy-naphthalene	Resorcin	Bisphenol A	-
Composition (part by weight)	Catalyst (Curing accelerator)	3.3	3.1	2.8	3.3	3	3.4	0.05
	Bisphenol A type epoxy resin	95	95	95	95	95	95	95
	Diaminodi-Phenylmethane	4	4	4	4	4	4	4
	Dicyandiamide	1	1	1	1	1	1	1
Glass transition temperature (°C)		148	145	141	144	140	150	102
Initial gel time (sec)		241	249	253	244	251	239	166
Gel time after storage treatment (sec)		239	242	243	239	248	232	101
Residual gel time percentage (%)		99	97	96	98	99	97	61

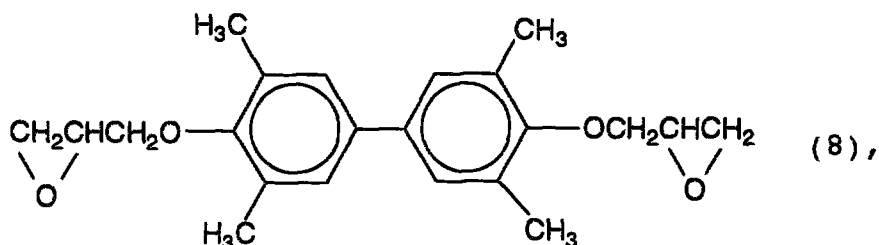
Table 4

		Example 18	Example 19	Example 20	Example 21	Example 22	Example 23	Comp.Ex. 4
	Catalyst species	Compound 1	Compound 2	Compound 8	Compound 4	Compound 10	Compound 12	2-Phenyl-4-methyl-imidazole
	Proton donor species	Naphthoic acid	Phenol	Naphthol	2,3-Dihydroxy-naphthalene	2,2'-Biphenol	Naphthoic acid	-
Composition (part by weight)	Catalyst (curing accelerator)	3.1	2.9	3	3.4	3.2	3.3	0.6
	BMI-80	100	100	100	100	100	100	100
Residual gel time percentage (%)		99	98	99	99	96	97	77

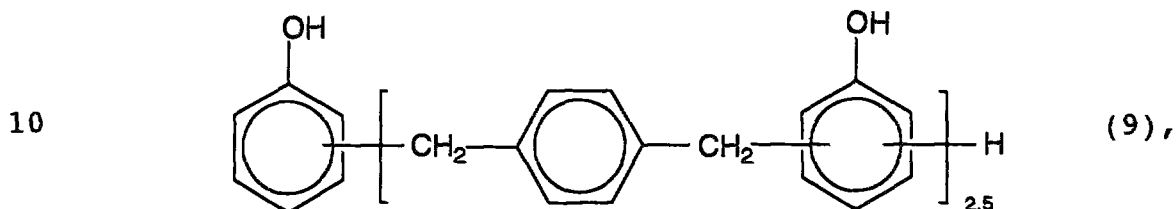
2. Examples relating to epoxy resin molding material and semiconductor device

Example 24

51 Parts of a resin comprising as the main component a biphenyl type epoxy resin represented by the formula (8) (epoxy equivalent: 185, melting point: 105°C):



49 parts of a phenolic resin represented by the formula (9) (hydroxyl group equivalent: 167, softening point: 73°C):



6.0 parts of Compound 1, 500 parts of fused spherical silica (average particle size: 15 μm), 2 parts of carbon black, 2 parts of a brominated bisphenol A type epoxy resin and 2 parts of carnauba wax were mixed and roll-milled at 95°C for 8 minutes using a hot roll, and thereafter, the resulting mixture was cooled and then pulverized to obtain a resin molding material. The resin molding material obtained was evaluated by the methods described below to obtain the results shown in Table 5.

Evaluation methods

(i') Spiral flow

Using a mold for spiral flow measurement according to EMMI-I-66, measurement was conducted at a mold
5 temperature of 175°C at an injection pressure of 70 kg/cm²
for a curing time of 2 minutes. The spiral flow is a
parameter of flow property and the larger the value, the
better the flow property. The unit is cm.

(ii') Shore D hardness

10 Molding was conducted at a mold temperature of
175°C at an injection pressure of 70 kg/cm² for a curing
time of 2 minutes and Shore D hardness was measured after
10 seconds from the opening of the mold. The value thus
obtained was evaluated as a curability. The Shore D
15 hardness is an index of curability and the larger the
value, the better the curability.

(iii') Storage stability at 30°C

After the storage at 30°C for one week, the spiral
flow was measured, and the percentage thereof based on the
20 spiral flow just after the preparation of the sample was
calculated. The unit is %.

(iv') Moisture resistance reliability

A 16-pin·DIP was encapsulated with a resin mold-
ing material at a mold temperature of 175°C at a pressure of
25 70 kg/cm² for a curing time of 2 minutes and then post-cured
at 175°C for 8 hours. Thereto was applied a voltage of 20 V
in water vapor at 125°C at a relative humidity of 100%,
after which conduction failure was examined. The time

until the failure took place in at least 8 of 15 packages evaluated was determined as a failure time. The unit is hour. Incidentally, the measurement time was 500 hours at longest and in the case where the number of failed packages at that time was less than 8, the failure time was shown as "more than 500 hours". The longer the failure time, the better the moisture resistance reliability.

Examples 25 to 31 and Comparative Examples 5 to 7

According to the formulations shown in Tables 5 and 6, resin molding materials were prepared and evaluated in the same manner as in Example 24. The results obtained are shown in Tables 5 and 6.

Incidentally, the crystalline epoxy resin A used in Example 25 was a mixture of 60% by weight of a resin comprising as the main component 4,4'-bis(2,3-epoxypropoxy)-3,3',5,5'-tetramethylstilbene with 40% by weight of a resin comprising as the main component 4,4'-bis(2,3-epoxypropoxy)-5-tertiary butyl-2,3',5'-trimethylstilbene (epoxy equivalent: 209, melting point: 120°C).

The o-cresol novolac type epoxy resin used in Example 26 had an epoxy equivalent of 200 and a softening point of 65°C (EOCN-1020-65 manufactured by NIPPON KAYAKU CO., LTD.).

The phenolic novolac resin used in Example 26 had a hydroxyl group equivalent of 104 and a softening point of 105°C.

When triphenylphosphine was used as the catalyst

(curing accelerator), the failure time in the moisture resistance reliability was good; however the storage stability at 30°C was lowered (cf. Comparative Example 5).

When Compound 13 and Compound 14, the proton
5 donors corresponding to which had an electrical conductivity of the extraction water of more than 1,000 $\mu\text{S}/\text{cm}$, were used as the curing accelerator, the moisture resistance reliability was lowered (cf. Comparative Examples 6 and 7).

Table 5

	Example 24	Example 25	Example 26	Example 27	Example 28	Example 29	Example 30	Example 31
Formula (8)	51			51	51	51	51	51
Crystalline epoxy resin A		56						
o-Cresol novolac type epoxy resin			67					
Formula (9)	49	44		49	49	49	49	49
Phenol novolac resin			33					
Compound 1	6.0	6.0	4.3					
Compound 2				2.9				
Compound 3					4.5			
Compound 4						3.3		
Compound 5							4.0	
Compound 7								4.7
Fused spherical silica	500	500	400	500	500	500	500	500
Carbon black	2	2	2	2	2	2	2	2
Brominated bisphenol A type epoxy resin	2	2	2	2	2	2	2	2
Carnauba wax	2	2	2	2	2	2	2	2
Spiral flow	98	92	120	102	95	100	97	101
Shore D hardness	85	88	83	83	83	80	81	82
Storage stability at 30°C	95	98	98	96	95	95	93	97
Moisture resistance reliability	>500	>500	>500	>500	>500	>500	>500	>500

Table 6

	Comp.Ex. 5	Comp.Ex. 6	Comp.Ex. 7
Formula (8)	51	51	51
Formula (9)	49	49	49
Triphenylphosphine	1.0		
Compound 13		2.1	
Compound 14			4.9
Fused spherical silica	500	500	500
Carbon black	2	2	2
Brominated bisphenol A type epoxy resin	2	2	2
Carnauba wax	2	2	2
Spiral flow	77	100	95
Shore D hardness	88	82	86
Storage stability at 30°C	52	88	87
Moisture resistance reliability	>500	200	250

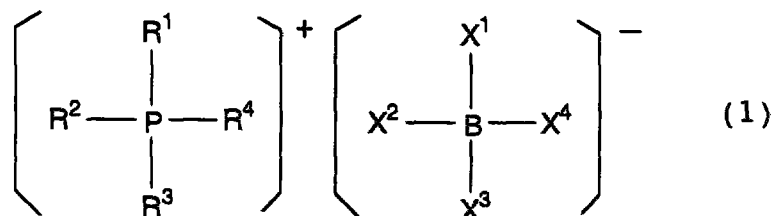
As clear from the above Examples, the latent catalyst of this invention and the thermosetting resin composition of this invention comprising the above catalyst are excellent in moisture resistance reliability, curability and storage stability at ordinary temperature. Moreover, the epoxy resin molding material of this invention comprising the above catalyst for encapsulating a semiconductor is extremely excellent in characteristics of preservation at ordinary temperature and moldability, and the semiconductor device in which the epoxy resin molding material is used, is excellent in moisture resistance

reliability and useful as a device responding to insertion mounting and surface mounting.



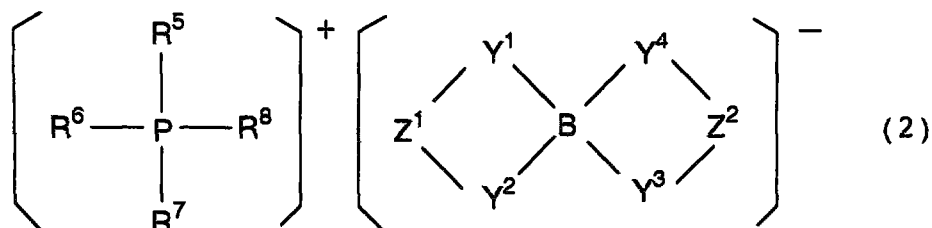
WHAT IS CLAIMED IS:

1. A latent catalyst composed of a phosphonium borate represented by the general formula (1):



wherein R^1 , R^2 , R^3 and R^4 may be the same as or different from one another and each is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond; X^1 , X^2 , X^3 and X^4 may be the same as or different from one another and at least one of them is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton and each of the others is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent aliphatic group, the above proton donors satisfying the condition that when 1 g of each of the proton donors is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus obtained becomes not more than 1,000 $\mu S/cm$.

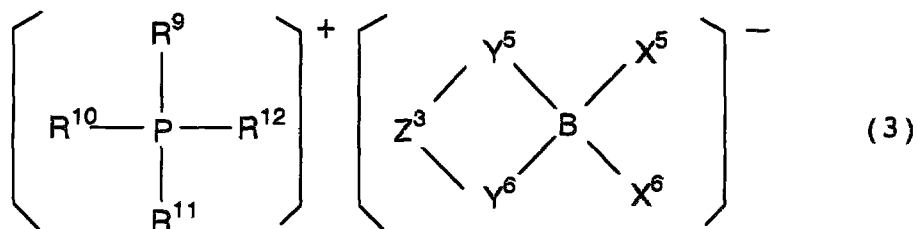
2. A latent catalyst composed of a phosphonium borate represented by the general formula (2):



wherein R^5 , R^6 , R^7 and R^8 may be the same as or different from one another and each is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond; Z^1 is an organic group bonding to Y^1 and Y^2 ; Z^2 is an organic group bonding to Y^3 and Y^4 ; each of Y^1 and Y^2 is a group formed when a monovalent, proton-donating substituent has liberated a proton and the substituents Y^1 and Y^2 in the same molecule are bonded to the boron atom to form a chelate structure; each of Y^3 and Y^4 is a group formed when a monovalent, proton-donating substituent has liberated a proton and the substituents Y^3 and Y^4 are bonded to the boron atom to form a chelate structure; Z^1 and Z^2 may be the same as or different from each other and also Y^1 , Y^2 , Y^3 and Y^4 may be the same as or different from one another; $HY^1Z^1Y^2H$ and $HY^3Z^2Y^4H$ which are the proton donors before the ligands $Y^1Z^1Y^2$ and $Y^3Z^2Y^4$ of boron are formed by liberation of the respective protons satisfying the condition that when 1 g of each of the proton donors is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus

obtained becomes not more than 1,000 $\mu\text{S}/\text{cm}$.

3. A latent catalyst composed of a phosphonium borate represented by the general formula (3):



wherein R^9 , R^{10} , R^{11} and R^{12} may be the same as or different from one another and each is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond; Z^3 is an organic group bonding to the substituents Y^5 and Y^6 ; Y^5 and Y^6 may be the same as or different from each other and each is a group formed when a monovalent proton-donating substituent has liberated a proton; the substituents Y^5 and Y^6 in the same molecule are bonded to the boron atom to form a chelate structure; X^5 and X^6 may be the same as or different from each other and each is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton, or is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group; $\text{HY}^5\text{Z}^3\text{Y}^6\text{H}$ which is the proton donor before the ligand $\text{Y}^5\text{Z}^3\text{Y}^6$ of boron is formed by the liberation of the protons and HX^5 and HX^6 which are the proton donors in the case where each of X^5 and X^6 is a group formed when a proton donor having at least one proton



capable of being liberated out of the molecule has liberated one proton, satisfying the condition that when 1 g of each of the proton donors is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus obtained becomes not more than 1,000 $\mu\text{S}/\text{cm}$.

4. A latent catalyst having a structure in which the recurring unit is a phosphonium borate consisting of a monovalent cation portion in which four groups are bonded to the phosphorus atom and a monovalent anion portion in which four groups are bonded to the boron atom and at least two of the recurring unit are connected through at least one of the four groups bonding to the boron atom, provided that the group through which the recurring units are connected is a group formed when one proton donor has liberated at least two protons and the group may be composed of the same kind or different kinds; the groups bonding to the phosphorus atom may be the same as or different from one another and each is a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and is bonded to the phosphorus atom to form a P-C bond; among the groups bonding to the boron atom, those which do not participate in the connection of the recurring units are each a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has



liberated one proton, or a monovalent, organic group having an aromatic ring or a heterocyclic ring or a monovalent, aliphatic group and they may be the same as or different from one another; the proton donors from which the groups bonding to the boron atom result satisfying the condition that when 1 g of each of the proton donors is mixed with 50 g of purified water and the resulting mixture is subjected to pressure cooker treatment at 125°C for 20 hours in a pressure cooker vessel, the electrical conductivity of the extraction water thus obtained becomes not more than 1,000 $\mu\text{S}/\text{cm}$.

5. The latent catalyst according to Claim 1, wherein the proton donor having at least one proton capable of being liberated out of the molecule is an aromatic carboxylic acid or a phenolic compound.

6. The latent catalyst according to Claim 2, wherein the proton donor represented by $\text{HY}^1\text{Z}^1\text{Y}^2\text{H}$ or $\text{HY}^3\text{Z}^2\text{Y}^4\text{H}$ is an aromatic carboxylic acid or a phenolic compound.

7. The latent catalyst according to Claim 3, wherein the proton donor represented by HX^5 or HX^6 in which each of X^5 and X^6 is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton, or represented by $\text{HY}^5\text{Z}^3\text{Y}^6\text{H}$ is an aromatic carboxylic acid or a phenolic compound.

8. The latent catalyst according to Claim 4, wherein the proton donor which does not participate in the connection of the recurring units or the proton donor which



participates in the connection of the recurring units is an aromatic carboxylic acid or a phenolic compound.

9. The latent catalyst according to Claim 1, wherein the proton donor having at least one proton capable of being liberated out of the molecule is an aromatic carboxylic acid or a phenolic compound which has at least one substituent selected from the group consisting of carboxyl group and phenolic hydroxyl group and in which two carboxyl groups or a carboxyl group and a phenolic hydroxyl group are not present at the mutually adjacent positions.

10. The latent catalyst according to Claim 3, wherein the proton donor represented by HX^5 or HX^6 in which each of X^5 and X^6 is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton is an aromatic carboxylic acid or a phenolic compound which has at least one substituent selected from the group consisting of carboxyl group and phenolic hydroxyl group and in which two carboxyl groups or a carboxyl group and a phenolic hydroxyl group are not present at the mutually adjacent positions.

11. The latent catalyst according to Claim 4, wherein the proton donor which does not participate in the connection of the recurring units is an aromatic carboxylic acid or a phenolic compound which has at least one substituent selected from the group consisting of carboxyl group and phenolic hydroxyl group and in which two carboxyl groups or a carboxyl group and a phenolic hydroxyl group are not present at the mutually adjacent positions.



12. The latent catalyst according to Claim 2, wherein the proton donor represented by $\text{HY}^1\text{Z}^1\text{Y}^2\text{H}$ or $\text{HY}^3\text{Z}^2\text{Y}^4\text{H}$ is an aromatic carboxylic acid or a phenolic compound which has at least two substituents selected from the group consisting of carboxyl group and phenolic hydroxyl group and in which two carboxyl groups or a carboxyl group and a phenolic hydroxyl group are not present at the mutually adjacent positions.

13. The latent catalyst according to Claim 3, wherein the proton donor represented by $\text{HY}^5\text{Z}^3\text{Y}^6\text{H}$ is an aromatic carboxylic acid or a phenolic compound which has at least two substituents selected from the group consisting of carboxyl group and phenolic hydroxyl group and in which two carboxyl groups or a carboxyl group and a phenolic hydroxyl group are not present at the mutually adjacent positions.

14. The latent catalyst according to Claim 4, wherein the proton donor which participates in the connection of the recurring units is an aromatic carboxylic acid or a phenolic compound which has at least two substituents selected from the group consisting of carboxyl group and phenolic hydroxyl group and in which two carboxyl groups or a carboxyl group and a phenolic hydroxyl group are not present at the mutually adjacent positions.

15. The latent catalyst according to Claim 1, wherein the proton donor having at least one proton capable of being liberated out of the molecule is a proton donor selected from the group consisting of substituted or unsubstituted benzoic acids, substituted or unsubstituted



naphthoic acids, substituted or unsubstituted phenols and substituted or unsubstituted naphthols.

16. The latent catalyst according to Claim 3, wherein the proton donor represented by HX^5 or HX^6 in which each of X^5 and X^6 is a group formed when a proton donor having at least one proton capable of being liberated out of the molecule has liberated one proton is a proton donor selected from the group consisting of substituted or unsubstituted benzoic acids, substituted or unsubstituted naphthoic acids, substituted or unsubstituted phenols and substituted or unsubstituted naphthols.

17. The latent catalyst according to Claim 4, wherein the proton donor which does not participate in the connection of the recurring units is a proton donor selected from the group consisting of substituted or unsubstituted benzoic acids, substituted or unsubstituted naphthoic acids, substituted or unsubstituted phenols and substituted or unsubstituted naphthols.

18. The latent catalyst according to Claim 2, wherein the proton donor represented by $HY^1Z^1Y^2H$ or $HY^3Z^2Y^4H$ is dihydroxybenzene, dihydroxynaphthalene, a bisphenol or a biphenol.

19. The latent catalyst according to Claim 3, wherein the proton donor represented by $HY^5Z^3Y^6H$ is dihydroxybenzene, dihydroxynaphthalene, a bisphenol or a biphenol.

20. The latent catalyst according to Claim 4, wherein the proton donor which participates in the connection of the recurring units is dihydroxybenzene, dihydroxy-



naphthalene, a bisphenol or a biphenol.

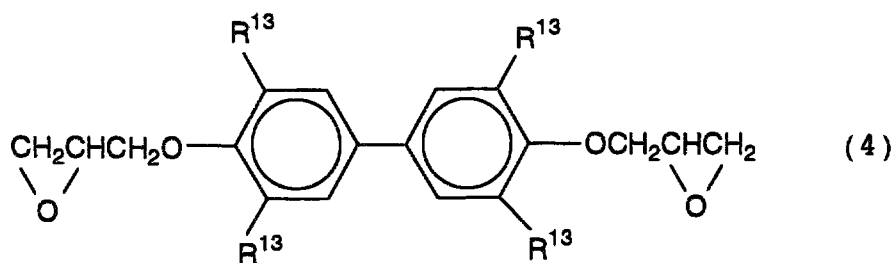
21. A thermosetting resin composition comprising 100 parts by weight of a thermosetting resin and 0.4 to 20 parts by weight of a latent catalyst selected from the group consisting of the latent catalysts according to Claims 1 to 4.

22. The thermosetting resin composition according to Claim 21, wherein the thermosetting resin is at least one member selected from the group consisting of epoxy resins and maleimide resins.

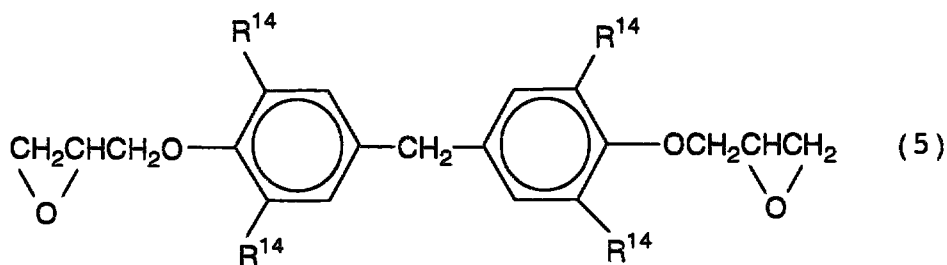
23. An epoxy resin molding material comprising, as the essential components, (A) an epoxy resin, (B) a phenolic resin, (C) the latent catalyst according to any one of Claims 1 to 20 and (D) an inorganic filler, the equivalent ratio between the epoxy group of the total epoxy resin and the phenolic hydroxyl group of the total phenolic resin being 0.5 to 2 and the amount of the inorganic filler (D) compounded being 200 to 2,400 parts by weight per 100 parts by weight of a total amount of the total epoxy resin and the total phenolic resin.

24. The epoxy resin molding material according to Claim 23, wherein the epoxy resin (A) is a crystalline epoxy resin having a melting point of 50-150°C.

25. The epoxy resin molding material according to Claim 24, wherein the crystalline epoxy resin having a melting point of 50-150°C is at least one member selected from the group consisting of epoxy resins represented by the general formulas (4) and (5):

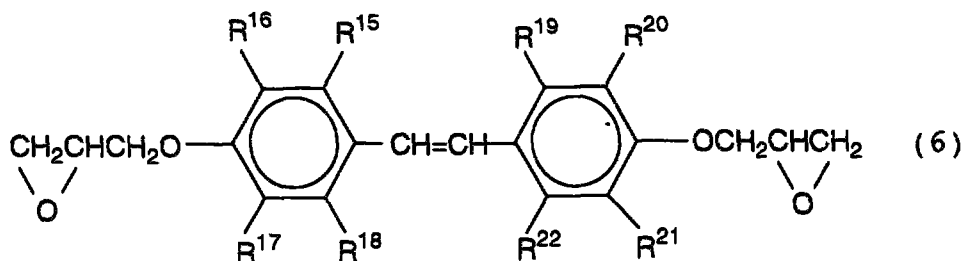


wherein each R^{13} is a group or atom selected from the group consisting of hydrogen atom, chain or cyclic alkyl groups having 1 to 6 carbon atoms, phenyl group and halogen atoms and the R^{13} groups or atoms may be the same as or different from one another, and

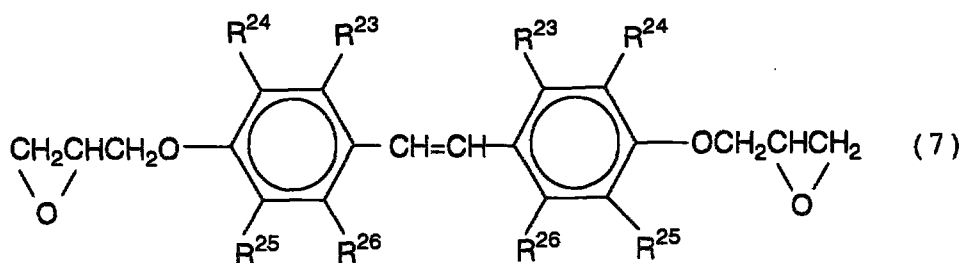


wherein each R^{14} is a group or atom selected from the group consisting of hydrogen atom, chain or cyclic alkyl groups having 1 to 6 carbon atoms, phenyl group and halogen atoms and the R^{14} groups or atoms may be the same as or different from one another.

26. The epoxy resin molding material according to Claim 24, wherein the crystalline epoxy resin having a melting point of 50-150°C is a mixture of a stilbene type epoxy resin represented by the general formula (6) and a stilbene type epoxy resin represented by the general formula (7):



wherein each of R^{15} to R^{22} represents independently a group or atom selected from the group consisting of hydrogen atom, chain or cyclic alkyl groups having 1 to 6 carbon atoms and halogen atoms, provided that the two aryl groups bonded to the carbon-carbon double bond are different from each other.



wherein each of R^{23} to R^{26} represents independently a group or atom selected from the group consisting of hydrogen atom, chain or cyclic alkyl groups having 1 to 6 carbon atoms and halogen atoms, provided that the two aryl groups bonded to the carbon-carbon double bond are the same as each other.

27. The epoxy resin molding material according to Claim 23, 24, 25 or 26, wherein the phenolic resin (B) is a phenolaralkyl resin.

28. A semiconductor device wherein a semiconductor is encapsulated with an epoxy resin molding material according to Claim 23, 24, 25, 26 or 27.